

Amperex® Electronic Corporation

A NORTH AMERICAN PHILIPS COMPANY

PROFESSIONAL TUBE DIVISION

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TUBE TYPES

4-125A/4D21

6155

The Amperex 4-125A/4D21 is a Premium version of the 4-125A, featuring a zirconium-coated heavy graphite anode for high intermittent overload capability and superior gas sorption for long life.

The 6155 is the same tube, but without the metal base. In most cases, the metal base, with its associated additional cost, is unnecessary except in critical neutralization applications. The tubes are intended for use as an RF or audio amplifier.

GENERAL CHARACTERISTICS

MECHANICAL

Base	giant 5 pin, medium shell
Cooling ¹	radiation and air
Maximum Operating Temperatures ¹	
Bulb	350°C
Plate Seal	220°C
Pin Seals	180°C
Mounting Position	vertical, base up or down
Accessories	
Plate Connector	S-25671
Socket	Johnson #122-275 or equiv.

ELECTRICAL

Filament	thoriated tungsten
Voltage	5.0 volts
Current	6.5 amps
Direct Interelectrode Capacitances	
Input	10.8 pF
Output	3.5 pF
Grid to Plate	0.05 pF
Amplification Factor, G ₂ to G ₁	6.2
Transconductance (I _b = 40 ma)	2200 μmhos

TYPE _____	TETRODE
COOLING _____	RADIATION
ENVELOPE _____	GLASS
MAX. PWR	
INPUT _____	625 W
MAX. PLATE	
DISS. _____	125 W
MAX. FREQ. _____	200 MHz



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¹ Radiation cooling of the tube is usually sufficient at frequencies below 50 MHz. Above 50 MHz, a low velocity air flow directed upon the anode seal and the bottom of the envelope is required, when tube is used at or near the maximum ratings.

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September, 1972

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AF Power Amplifier and Modulator Class AB₁

Maximum Ratings, Absolute Values

	<u>CCS</u>
DC Plate Voltage	3000 volts
DC Grid No. 2 Voltage	600 volts
DC Grid No. 1 Voltage	-500 volts
Maximum Signal DC Plate Current ³	225 mA
Maximum Signal Grid No. 2 Input ³	20 watts
Plate Dissipation ³	125 watts

Typical Operation

Unless otherwise specified, values are for two tubes

	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>
DC Plate Voltage	1,500	2,000	2,500 volts
DC Grid No. 2 Voltage	600	600	600 volts
DC Grid No. 1 Voltage	-94	-95.5	-97 volts
Peak AF Grid No. 1 to Grid No. 1 Voltage	185	186	190 volts
Zero Signal DC Plate Current	60	60	60 mA
Maximum Signal DC Plate Current	208	222	216 mA
Zero Signal DC Grid No. 2 Current	0.3	0.2	0.2 mA
Maximum Signal DC Grid No. 2 Current	27	24	26 mA
Effective Load Resistance, Plate to Plate	12,000	17,600	25,000 ohms
Maximum Signal Driving Power ⁴	0	0	0 watts
Maximum Signal Power Output	170	260	345 watts

AF Power Amplifier and Modulator Class AB₂

Maximum Ratings, Absolute Values

	<u>CCS</u>
DC Plate Voltage	3000 volts
DC Grid No. 2 Voltage	400 volts
DC Grid No. 1 Voltage	-500 volts
Maximum Signal DC Plate Current ³	225 mA
Maximum Signal Grid No. 2 Input ³	20 watts
Plate Dissipation ³	125 watts

² Maximum ratings apply up to 120 megahertz. The tube may be operated at higher frequencies provided the maximum values of plate voltage and power input are reduced according to the tabulation below (other maximum ratings are the same as shown above). Special attention should be given to adequate ventilation of the bulb at these frequencies.

Frequency	120	170	200 MHz
Rated Plate Input			
Class B	200	190	150 watts
Class C Plate Telephony	415	375	290 watts
Class C Telegraphy	625	560	435 watts
Rated Plate Voltage			
Class B	3000	2500	2200 volts
Class C Plate Telephony	2500	2100	1800 volts
Class C Telegraphy	3000	2500	2200 volts

³ Averaged over any audio-frequency cycle of sine-wave form.

⁴ The effective resistance per grid No. 1 circuit of the class AB₁ stage should be kept below 0.15 megohms.

Typical Operation

Unless otherwise specified, values are for two tubes

	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>
DC Plate Voltage	1,500	2,000	2,500 volts
DC Grid No. 2 Voltage	350	350	350 volts
DC Grid No. 1 Voltage	-48	-50	-51 volts
Peak AF Grid No. 1 to Grid No. 1 Voltage	330	296	240 volts
Zero Signal DC Plate Current	60	60	60 mA
Maximum Signal DC Plate Current	455	395	302 mA
Zero Signal DC Grid No. 2 Current	0.5	0.3	0.2 mA
Maximum Signal DC Grid No. 2 Current	84	64	36 mA
Effective Load Resistance, Plate to Plate	7,200	12,000	20,000 ohms
Maximum Signal Driving Power ⁵	4.8	3.2	1.8 watts
Maximum Signal Power Output	455	550	550 watts

RF Power Amplifier Class B

Carrier conditions per tube for use with a maximum modulation factor of 1.0

Maximum Ratings, Absolute Values²

	<u>CCS</u>
DC Plate Voltage	3000 volts
DC Grid No. 2 Voltage	400 volts
DC Plate Current	135 mA
Plate Input	200 watts
Grid No. 2 Input	14 watts
Plate Dissipation	125 watts

Typical Operation

	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>
DC Plate Voltage	2000	2500	3000 volts
DC Grid No. 2 Voltage	350	350	350 volts
DC Grid No. 1 Voltage	-50	-50	-50 volts
Peak RF Grid No. 1 Voltage	65	55	50 volts
DC Plate Current	83	70	60 mA
DC Grid No. 2 Current	1.5	1	1 mA
DC Grid No. 1 Current (approx.) ⁶	4	4	4.5 mA
Driving Power (approx.) ⁶	0.52	0.44	0.45 watt
Power Output (approx.)	54	55	58 watts

Plate and Screen Grid Modulated RF Power Amplifier Class C-Telephony

Carrier conditions per tube for use with a maximum modulation factor of 1.0

Maximum Ratings, Absolute Values²

	<u>CCS</u>
DC Plate Voltage	2500 volts
DC Grid No. 2 Voltage	400 volts
DC Grid No. 1 Voltage	-500 volts
DC Plate Current	200 mA
DC Grid No. 1 Current	15 mA
Plate Input	415 watts
Grid No. 2 Input	20 watts
Plate Dissipation	83 watts

⁵ Driver stage should be capable of supplying the No. 1 grids of the class AB₂ stage with the specific driving power at low distortion. When a bias supply is used, the DC-resistance of the bias source should not exceed 250 ohms.

⁶ At crest of audio-frequency cycle with modulation factor of 1.0

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Typical Operation

	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>
DC Plate Voltage	1500	2000	2500 volts
DC Grid No. 2 Voltage	300	350	350 volts
DC Grid No. 1 Voltage	-150	-220	-210 volts
Peak AF Grid No. 2 Voltage	255	300	300 volts
Peak RF Grid No. 1 Voltage	250	390	380 volts
DC Plate Current	160	150	152 mA
DC Grid No. 2 Current	33	33	30 mA
DC Grid No. 1 Current (approx.)	10	5	4.5 mA
Driving Power (approx.)	2.5	2	1.7 watts
Power Output (approx.)	157	225	300 watts
Modulation Factor	100	100	100 %
Modulation Power	120	150	190 watts
Efficiency	65	75	79 %

RF Power Amplifier and Oscillator Class C-Telegraphy

Key-down conditions per tube without amplitude modulation⁷

Maximum Ratings, Absolute Values²

	<u>CCS</u>
DC Plate Voltage	3000 volts
DC Grid No. 2 Voltage	400 volts
DC Grid No. 1 Voltage	-500 volts
DC Plate Current	225 mA
DC Grid No. 1 Current	15 mA
Plate Input	625 watts
Grid No. 2 Input	20 watts
Plate Dissipation	125 watts

Typical Operation

	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>	<u>CCS</u>
DC Plate Voltage	1500	2000	2500	3000 volts
DC Grid No. 2 Voltage	350	350	350	350 volts
DC Grid No. 1 Voltage	-150	-100	-150	-150 volts
Peak RF Grid No. 1 Voltage	225	260	330	300 volts
DC Plate Current	110	200	200	167 mA
DC Grid No. 2 Current	56	50	40	30 mA
DC Grid No. 1 Current (approx.)	8	9	9	6.5 mA
Driving Power (approx.)	1.7	2.4	3.0	2.0 watts
Power Output (approx.)	110	275	375	375 watts
Efficiency	67	69	75	75 %

Class AB₁ Linear RF Amplifier Single Sideband Suppressed Carrier Operation

Maximum Ratings, Absolute Values²

	<u>CCS</u>
DC Plate Voltage	3000 volts
DC Grid No. 2 Voltage	660 volts
DC Grid No. 1 Voltage	-500 volts
DC Plate Current	225 mA
Plate Input	625 watts
Plate Dissipation	125 watts
Grid No. 2 Input	20 watts
DC Grid No. 1 Current	15 mA

⁷ Modulation essentially negative may be used if the positive peak of the envelope does not exceed 115 per cent of the carrier conditions.

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Typical Operation Single Tone and/or Two Tone Modulation

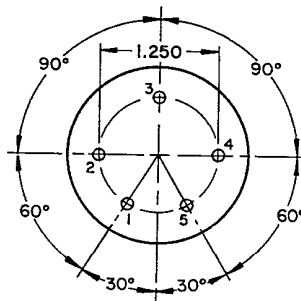
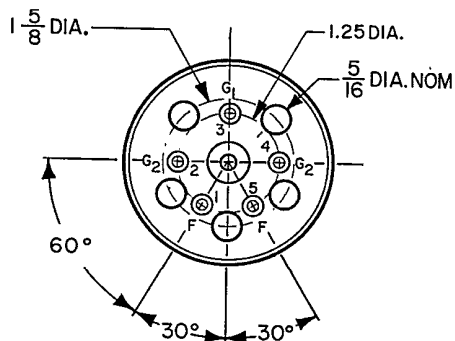
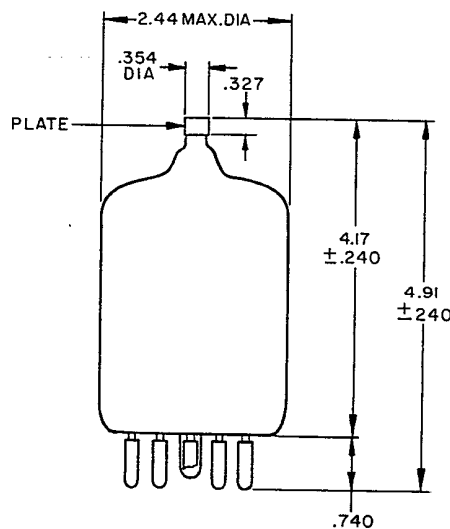
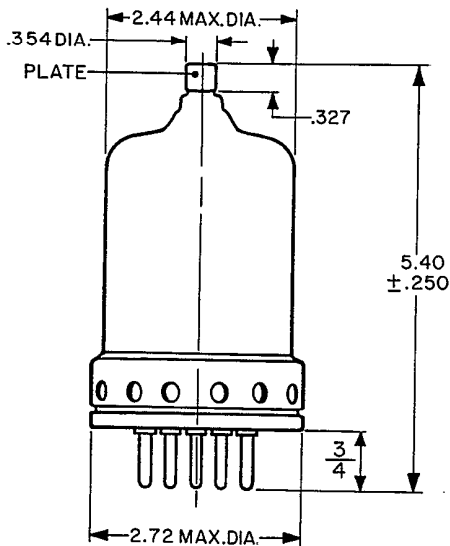
	CCS	CCS	CCS	CCS
DC Plate Voltage	3,000	2,500	2,000	1,500 volts
DC Grid No. 2 Voltage	600	600	600	600 volts
DC Grid No. 1 Voltage	-108	-103	-99	-100 volts
Zero Signal DC Plate Current	23	27	30	26 mA
Zero Signal DC Grid No. 2 Current	2	2	1	1 mA
Effective RF Load Resistance	15,000	13,000	11,000	7,500 ohms

Single Tone Modulation

Maximum Signal DC Plate Current	115	111	103	114 mA
Maximum Signal DC Grid No. 2 Current	14	18	27	16 mA
Maximum Signal DC Grid No. 1 Current	0	0	0	0 mA
Maximum Signal Peak RF Grid Voltage	108	103	99	100 volts
Maximum Signal Driving Power	0	0	0	0 watts
Maximum Signal Plate Power Output	228	162	142	98 watts

Two Tone Modulation

Average DC Plate Current	77	73	74	77 mA
Average DC Grid No. 2 Current	7	5	11	8 mA
Average DC Grid No. 1 Current	0	0	0	0 mA
Maximum Resultant Peak RF Grid Voltage	108	103	99	100 volts
Average Plate Power Output	103	75	64	44 watts
Peak Envelope Plate Power Output	206	150	128	88 watts
3rd Order Intermodulation Distortion	30	32	34	35 dB



GIANT 5 PIN BASE
5 PINS, .187 ± .003 DIA.

PIN CONNECTIONS

- 1 - FILAMENT
- 2 - GRID NO. 2
- 3 - GRID NO. 1
- 4 - GRID NO. 2
- 5 - FILAMENT

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NOTE: IN ORDER TO PREVENT OVERHEATING OF THE GRID NO. 2 PINS IT IS RECOMMENDED THAT BOTH PINS BE CONNECTED TO THE CIRCUIT.

